

## Power Supply Tracking Controller

August 2003

### FEATURES

- Flexible Power Supply Tracking
- Tracks Both Up and Down
- Power Supply Sequencing
- Supply Stability is Not Affected
- Controls Two Supplies Without Series FETs
- Controls a Third Supply with a Series FET
- Adjustable Ramp Rates
- Electronic Circuit Breaker
- Available in 10-Lead MS Package

### APPLICATIONS

- $V_{CORE}$  and  $V_{I/O}$  Supply Tracking
- Microprocessor, DSP and FPGA Supplies
- Servers
- Communication Systems

### DESCRIPTION

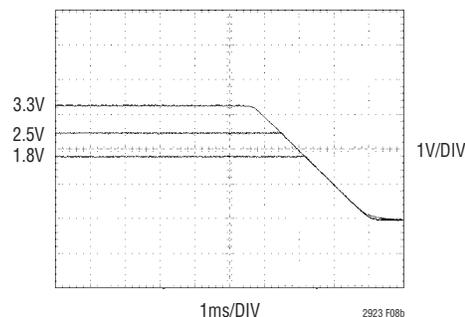
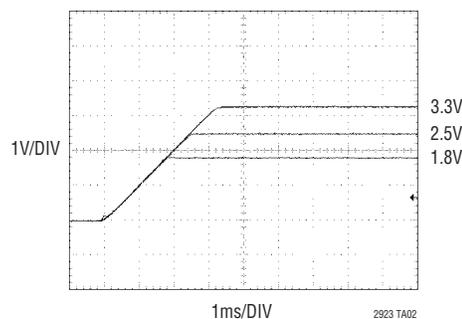
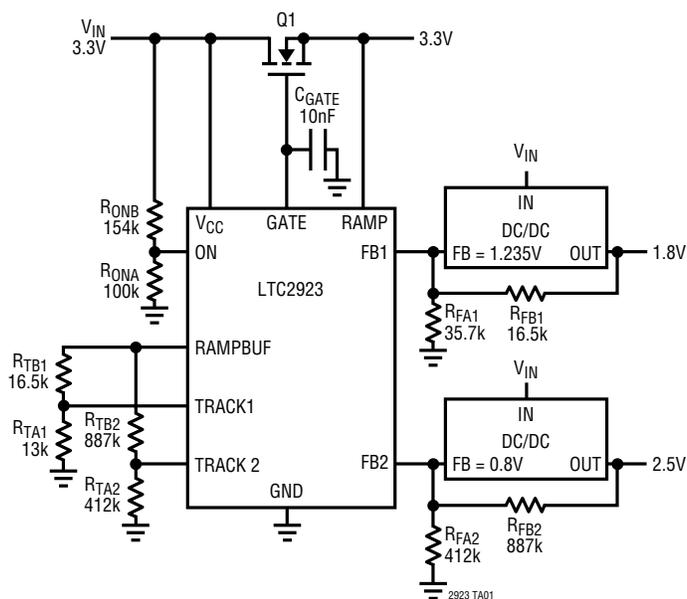
The LTC<sup>®</sup>2923 provides a simple solution to power supply tracking and sequencing requirements. By selecting a few resistors, the supplies can be configured to ramp-up and ramp-down together with voltage offsets, with time delays or with differing ramp rates.

By introducing currents into the feedback nodes of two independent supplies, the LTC2923 causes their outputs to track without inserting any pass element losses. Because the currents are controlled in an open-loop manner, the LTC2923 does not affect the transient response or stability of the supplies. Furthermore, it presents a high impedance when power-up is complete, effectively removing it from the DC/DC circuit.

For systems that require a third supply, or when a supply does not allow direct access to its feedback resistors, one supply can be controlled with a series FET. When the FET is used, an electronic circuit breaker provides protection from short-circuit conditions.

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### TYPICAL APPLICATION



## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage ( $V_{CC}$ )	-0.3V to 10V
Input Voltages	
ON	-0.3V to 10V
TRACK1, TRACK2	-0.3V to $V_{CC} + 0.3V$
RAMP	-0.3V to $V_{CC} + 1V$
Output Voltages	
FB1, FB2	-0.3V to 10V
RAMPBUF	-0.3V to $V_{CC} + 0.3V$
GATE (Note 2)	-0.3V to 11.5V
Average Current	
TRACK1, TRACK2	5mA
FB1, FB2	5mA
RAMPBUF	5mA
Operating Temperature Range	
LTC2923C	0°C to 70°C
LTC2923I	-40°C to 85°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

## PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LTC2923CMS LTC2923IMS
	MS PART MARKING
	LTAED LTAEE

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $2.9V < V_{CC} < 5.5V$  unless otherwise noted (Note 3).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{CC}$	Input Supply Range		● 2.9		5.5	V
$I_{CC}$	Input Supply Current	$I_{FBx} = 0, I_{TRACKx} = 0$ $I_{FBx} = -1\text{mA}, I_{TRACKx} = -1\text{mA},$ $I_{RAMPBUF} = -2\text{mA}$	● 5	1.3 7	3 10	mA mA
$V_{CC(UVL)}$	Input Supply Undervoltage Lockout	$V_{CC}$ Rising	● 2.2	2.5	2.7	V
$\Delta V_{CC(UVLHYST)}$	Input Supply Undervoltage Lockout Hysteresis			25		mV
$\Delta V_{GATE}$	External N-Channel Gate Drive ( $V_{GATE} - V_{CC}$ )	$I_{GATE} = -1\mu\text{A}$	● 5	5.5	6	V
$I_{GATE}$	GATE Pin Current	Gate On, $V_{GATE} = 0V$ , No Faults Gate Off, $V_{GATE} = 5V$ , No Faults Gate Off, $V_{GATE} = 5V$ , Short-Circuit Fault	● -7 ● 5	-10 10 20	-13 13 40	$\mu\text{A}$ $\mu\text{A}$ mA
$V_{ON(TH)}$	ON Pin Threshold Voltage	$V_{ON}$ Rising	● 1.212	1.230	1.248	V
$\Delta V_{ON(HYST)}$	ON Pin Hysteresis		● 30	75	150	mV
$V_{ON(FC)}$	ON Pin Fault Clear Threshold Voltage		● 0.3	0.4	0.5	V
$I_{ON}$	ON Pin Input Current	$V_{ON} = 1.2V, V_{CC} = 5.5V$	●	0	$\pm 100$	nA
$\Delta V_{DS(TH)}$	FET Drain-Source Overcurrent Voltage Threshold ( $V_{CC} - V_{RAMP}$ )		● 160	200	240	mV
$I_{RAMP}$	RAMP Pin Input Current	$0V < RAMP < V_{CC}, V_{CC} = 5.5V$	●	0	$\pm 1$	$\mu\text{A}$
$V_{RAMPBUF(OL)}$	RAMPBUF Low Voltage	$I_{RAMPBUF} = 2\text{mA}$	●	90	150	mV
$V_{RAMPBUF(OH)}$	RAMPBUF High Voltage ( $V_{CC} - V_{RAMPBUF}$ )	$I_{RAMPBUF} = -2\text{mA}$	●	100	200	mV
$V_{OS}$	Ramp Buffer Offset ( $V_{RAMPBUF} - V_{RAMP}$ )	$V_{RAMPBUF} = V_{CC}/2, I_{RAMPBUF} = 0A$	● -30	0	30	mV

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $2.9\text{V} < V_{CC} < 5.5\text{V}$  unless otherwise noted (Note 3).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
$I_{\text{ERROR}}(\%)$	$I_{\text{FBx}}$ to $I_{\text{TRACKx}}$ Current Mismatch $I_{\text{ERROR}}(\%) = (I_{\text{FBx}} - I_{\text{TRACKx}})/I_{\text{TRACKx}}$	$I_{\text{TRACKx}} = -10\mu\text{A}$	●	0	$\pm 5$	%	
		$I_{\text{TRACKx}} = -1\text{mA}$	●	0	$\pm 5$	%	
$V_{\text{TRACKx}}$	TRACK Pin Voltage	$I_{\text{TRACKx}} = -10\mu\text{A}$	●	0.776	0.8	0.824	V
		$I_{\text{TRACKx}} = -1\text{mA}$	●	0.776	0.8	0.824	V
$I_{\text{FB}}(\text{LEAK})$	$I_{\text{FB}}$ Leakage Current	$V_{\text{FB}} = 1.5\text{V}$ , $V_{\text{CC}} = 5.5\text{V}$	●	$\pm 1$	$\pm 100$	nA	
$V_{\text{FB}}(\text{CLAMP})$	$V_{\text{FB}}$ Clamp Voltage	$1\mu\text{A} < I_{\text{FB}} < 1\text{mA}$	●	1.5	1.7	2	V
$t_{\text{PSC}}$	Short-Circuit Propagation Delay $V_{\text{DS}}$ High to GATE Low	$V_{\text{DS}} = V_{\text{CC}}$ , $V_{\text{CC}} = 2.9\text{V}$		10	20	$\mu\text{s}$	

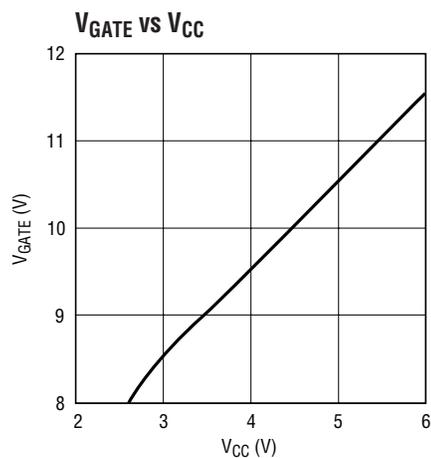
**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** The GATE pin is internally limited to a minimum of 11.5V. Driving this pin to voltages beyond the clamp may damage the part.

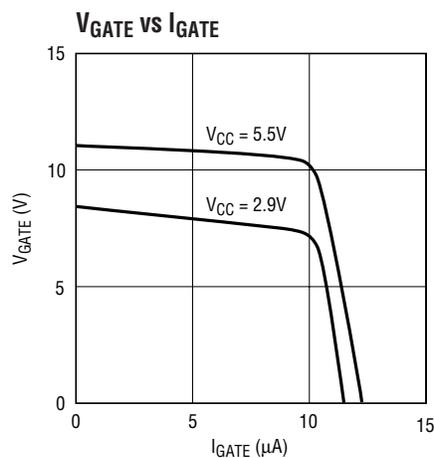
**Note 3:** All currents into the device pins are positive; all currents out of device pins are negative. All voltages are referenced to ground unless otherwise specified.

## TYPICAL PERFORMANCE CHARACTERISTICS

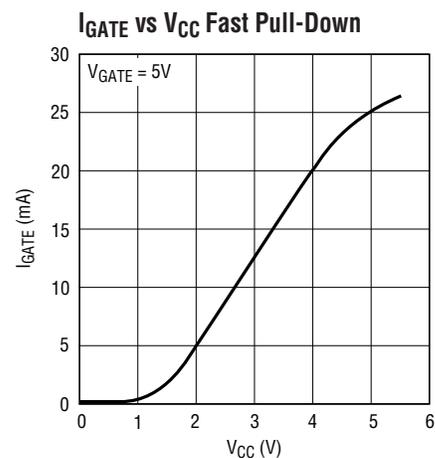
Specifications are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.



2923 G01



2923 G02



2923 G03

## PIN FUNCTIONS

**V<sub>CC</sub> (Pin 1):** Positive Supply Input Pin. The operating supply input range is 2.9V to 5.5V. An undervoltage lockout circuit resets the part when the supply is below 2.5V. V<sub>CC</sub> should be bypassed to GND with a 0.1μF capacitor.

**ON (Pin 2):** On Control Input. The ON pin has a threshold of 1.23V with 75mV of hysteresis. An active high will cause 10μA to flow from the GATE pin, ramping up the supplies. An active low pulls 10μA from the GATE pin, ramping the supplies down. Pulling the ON pin below 0.4V resets the electronic circuit breaker in the LTC2923. If a resistive divider connected to V<sub>CC</sub> drives the ON pin, the supplies will automatically start up when V<sub>CC</sub> is fully powered.

**TRACK1, TRACK2 (Pins 3, 4):** Tracking Control Input Pin. A resistive divider between RAMPBUF, TRACKx and GND determines the tracking profile of OUTx (see Applications Information). TRACKx pulls up to 0.8V and the current supplied at TRACKx is mirrored at FBx. The TRACKx pin is capable of supplying at least 1mA when V<sub>CC</sub> = 2.9V. It may be capable of supplying up to 10mA when the supply is at 5.5V, so care should be taken not to short this pin for extended periods. Limit the capacitance at the TRACKx pin to less than 25pF. Float the TRACK pins if unused.

**RAMPBUF (Pin 5):** Ramp Buffer Output. Provides a low impedance buffered version of the signal on the RAMP pin. This buffered output drives the resistive dividers that connect to the TRACKx pins. Limit the capacitance at the RAMPBUF pin to less than 100pF.

**GND (Pin 6):** Circuit Ground.

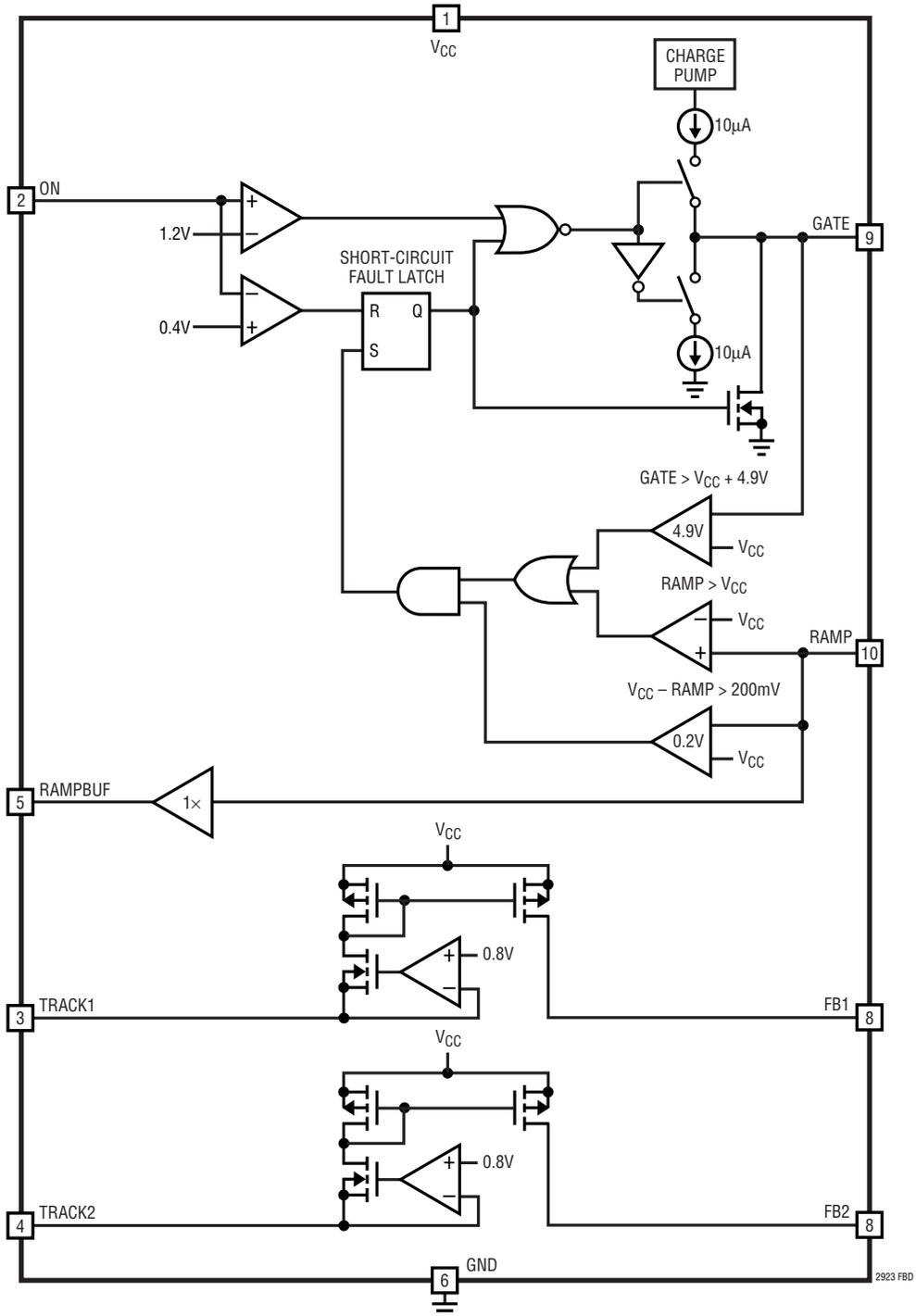
**FB1, FB2 (Pins 8, 7):** Feedback Control Output. FBx pulls up on the feedback node of slave supplies. Tracking is

achieved by mirroring the current from TRACKx into FBx. If the appropriate resistive divider connects RAMPBUF and TRACKx, the FBx current will force OUTx to track RAMP. To prevent damage to the slave supply, the FBx pin will not force the slave's feedback node above 1.7V. In addition, it will not actively sink current from this node even when the LTC2923 is unpowered. Float the FB pins if unused.

**GATE (Pin 9):** Gate Drive for External N-Channel FET. When the ON pin is high, an internal 10μA current source charges the gate of the external N-channel MOSFET. A capacitor connected from GATE to GND sets the ramp rate. An internal charge pump guarantees that GATE will pull up to 4.5V above RAMP ensuring that logic level N-channel FETs are fully enhanced. When the ON pin is pulled low, the GATE pin is pulled to GND with a 10μA current source. Under a short-circuit condition, the electronic circuit breaker in the LTC2923 pulls the GATE low immediately with 20mA. Tie GATE to GND if unused.

**RAMP (Pin 10):** Ramp Buffer Input. When the RAMP pin is connected to the source of the external N-channel FET, the slave supplies track the FET's source as it ramps up and down. If the GATE is fully enhanced (GATE > V<sub>CC</sub> + 4.9V) and (V<sub>CC</sub> – RAMP > 200mV) indicates a shorted output, then the electronic circuit breaker trips and GATE quickly pulls low with 20mA. The GATE will not ramp up again until ON is pulled below 0.4V and then above 1.23V. Alternatively, when no external FET is used, the RAMP pin can be tied directly to the GATE pin. In this configuration, the supplies track the capacitor on the GATE pin as it is charged and discharged by the 10μA current source controlled by the ON pin.

# FUNCTIONAL BLOCK DIAGRAM



2923 FBD

## APPLICATIONS INFORMATION

### Power Supply Tracking and Sequencing

The LTC2923 handles a variety of power-up profiles to satisfy the requirements of digital logic circuits including FPGAs, PLDs, DSPs and microprocessors. These requirements fall into one of the four general categories illustrated in Figures 1 to 4.

Some applications require that the potential difference between two power supplies must never exceed a specified voltage. This requirement applies during power-up and power-down as well as during steady-state operation, often to prevent destructive latch-up in a dual supply ASIC. Typically, this is achieved by ramping the supplies up and down together (Figure 1). In other applications it is desirable to have the supplies ramp up and down with fixed voltage offsets between them (Figure 2) or to have them ramp up and down ratiometrically (Figure 3).

Certain applications require one supply to come up after another. For example, a system clock may need to start before a block of logic. In this case, the supplies are sequenced as in Figure 4 where the 2.5V supply ramps up after the 1.8V supply is completely powered.

### Operation

The LTC2923 provides a simple solution to all of the power supply tracking and sequencing profiles shown in Figures 1 to 4. A single LTC2923 controls up to three supplies with two “slave” supplies that track a “master” signal. With just two resistors, a slave supply is configured to ramp up as a function of the master signal. This master signal can be a third supply that is ramped up through an external FET, whose ramp rate is set with a single capacitor, or it can be a signal generated by tying the GATE and RAMP pins to an external capacitor.

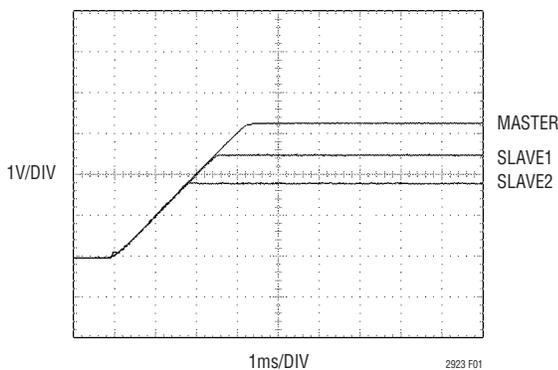


Figure 1. Coincident Tracking

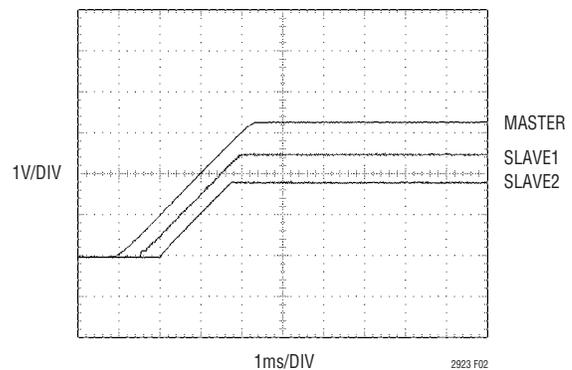


Figure 2. Offset Tracking

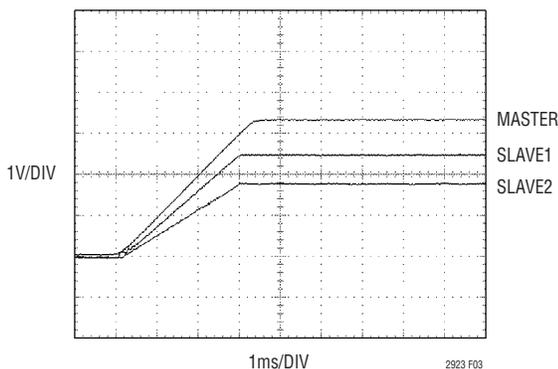


Figure 3. Ratiometric Tracking

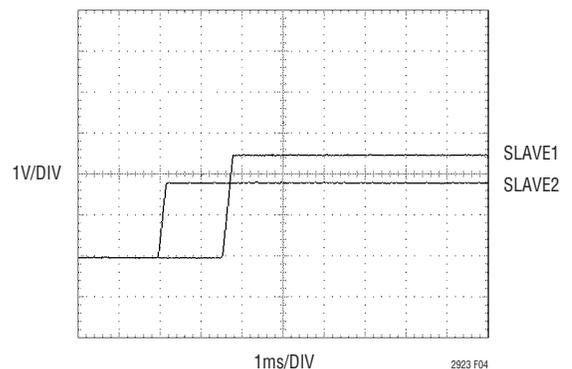


Figure 4. Supply Sequencing

## APPLICATIONS INFORMATION

### Tracking Cell

The LTC2923's operation is based on the tracking cell shown in Figure 5, which uses a proprietary wide-range current mirror. The tracking cell shown in Figure 5 serves the TRACK pin at 0.8V. The current supplied by the TRACK pin is mirrored at the FB pin to establish a voltage at the output of the slave supply. The slave output voltage varies with the master signal, enabling the slave supply to be controlled as a function of the master signal with terms set by  $R_{TA}$  and  $R_{TB}$ . By selecting appropriate values of  $R_{TA}$  and  $R_{TB}$ , it is possible to generate any of the profiles in Figures 1 to 4.

### Controlling the Ramp-Up and Ramp-Down Behavior

The operation of the LTC2923 is most easily understood by referring to the simplified functional diagram in Figure 6. When the ON pin is low, the GATE pin is pulled to ground causing the master signal to remain low. Since the currents through  $R_{TB1}$  and  $R_{TB2}$  are at their maximum when the master signal is low, the currents from FB1 and FB2 are also at their maximum. These currents drive the slaves' outputs to their minimum voltages.

When the ON pin rises above 1.23V, the master signal rises and the slave supplies track the master signal. The ramp rate is set by an external capacitor driven by a  $10\mu\text{A}$  current source from an internal charge pump. If no external FET is used, the ramp rate is set by tying the RAMP and

GATE pins together at one terminal of the external capacitor (see the Ratiometric Tracking Example).

In a properly designed system, when the master signal has reached its maximum voltage the current from the TRACKx pin is zero. In this case, there is no current from the FBx pin and the LTC2923 has no effect on the output voltage accuracy, transient response or stability of the slave supply.

When the ON pin falls below  $V_{ON(TH)} - \Delta V_{ON(HYST)}$ , typically 1.225V, the GATE pin pulls down with  $10\mu\text{A}$  and the master signal and the slave supplies will fall at the same rate as they rose previously.

The ON pin can be controlled by a digital I/O pin or it can be used to monitor an input supply. By connecting a resistive divider from an input supply to the ON pin, the supplies will ramp up only after the monitored supply has reached a preset voltage.

### Optional External FET

The Coincident Tracking Example (Figures 8 and 9) illustrates how an optional external N-channel FET can ramp up a single supply that becomes the master signal. When used, the FET's gate is tied to the GATE pin and its source is tied to the RAMP pin. Under normal operation, the GATE pin sources or sinks  $10\mu\text{A}$  to ramp the FET's gate up or down at a rate set by the external capacitor connected to the GATE pin.

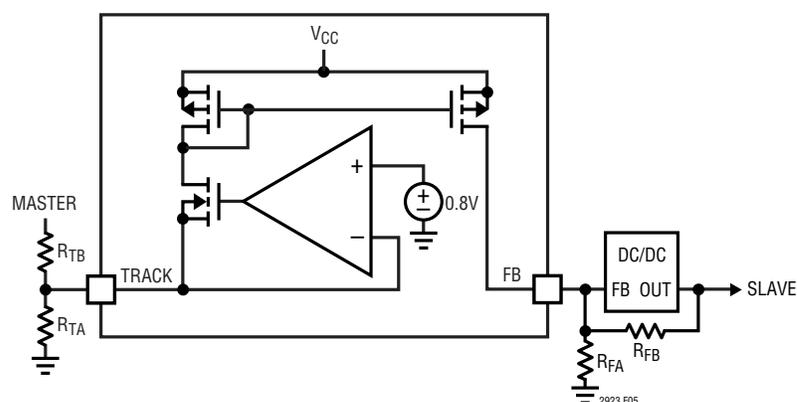


Figure 5. Simplified Tracking Cell

## APPLICATIONS INFORMATION

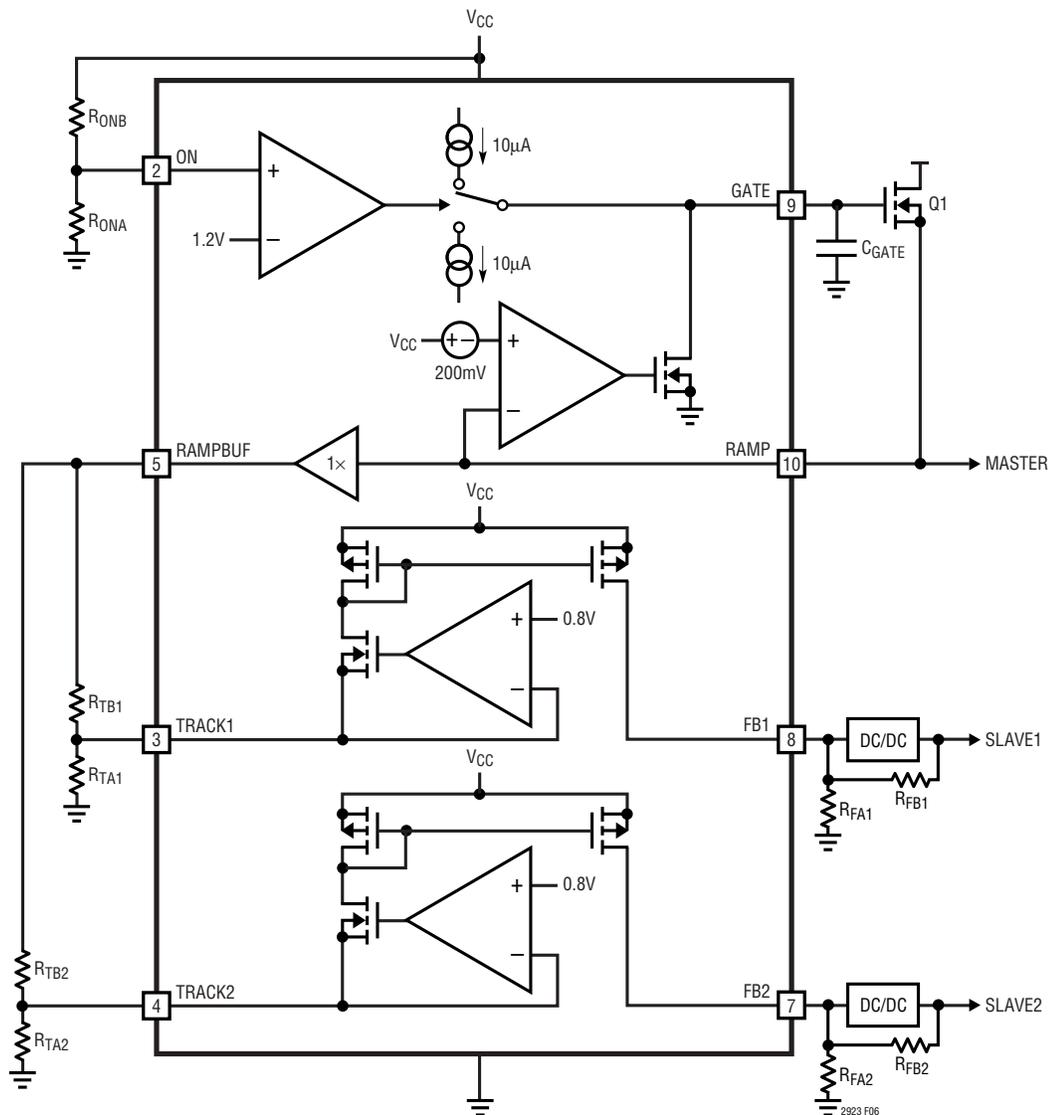


Figure 6. Simplified Functional Diagram

The LTC2923 features an electronic circuit breaker function that protects the optional series FET against short circuits. When the FET is fully enhanced ( $GATE > V_{CC} + 4.9V$ ), the electronic circuit breaker is enabled. Then, if the voltage across the FET ( $V_{DS}$ ) exceeds 200mV as measured from  $V_{CC}$  to the RAMP pin for more than about 10µs the gate of the FET is pulled down with 20mA, turning it off. Because the slaved supplies track the RAMP pin, they are pulled low by the tracking circuit when a short-circuit fault occurs. Following a short-circuit fault, the FET is latched off until the fault is cleared by pulling the ON pin below 0.4V.

### The Ramp Buffer

The RAMPBUF pin provides a buffered version of the RAMP pin voltage that drives the resistive dividers on the TRACKx pins. When there is no external FET, it provides up to 2mA to drive the resistors even though the GATE pin only supplies 10µA. The RAMPBUF pin also proves useful in systems with an external FET. Since the track cell in the simplified functional diagram above drives 0.8V on the TRACKx pins, if  $R_{TBx}$  is connected directly to the FET's source, the TRACKx pin could potentially pull up the FET's source towards 0.8V when the FET is off. RAMPBUF blocks this path.

## APPLICATIONS INFORMATION

### 3-Step Design Procedure

The following 3-step procedure allows one to complete a design for any of the tracking or sequencing profiles shown in Figures 1 to 4. A basic three supply application circuit is shown in Figure 7.

#### 1. Set the ramp rate of the master signal.

Solve for the value of  $C_{GATE}$ , the capacitor on the GATE pin, based on the desired ramp rate (V/s) of the master supply,  $S_M$ .

$$C_{GATE} = \frac{I_{GATE}}{S_M} \text{ where } I_{GATE} \approx 10\mu A \quad (1)$$

If the external FET has a gate capacitance comparable to  $C_{GATE}$ , then the external capacitor's value should be reduced to compensate for the FET's gate capacitance.

If no external FET is used, tie the GATE and RAMP pins together.

#### 2. Solve for the pair of resistors that provide the desired ramp rate of the slave supply, assuming no delay.

Choose a ramp rate for the slave supply,  $S_S$ . If the slave supply ramps up coincident with the master supply or with a fixed voltage offset, then the ramp rate equals the master supply's ramp rate. Be sure to use a fast enough ramp rate for the slave supply so that it will finish ramping before the master supply has reached its final supply value. If not, the slave supply will be held below the intended regulation value by the master supply. Use the following formulas to determine the resistor values for the desired ramp rate, where  $R_{FB}$  and  $R_{FA}$  are the feedback resistors in the slave supply and  $V_{FB}$  is the feedback reference voltage of the slave supply:

$$R_{TB} = R_{FB} \cdot \frac{S_M}{S_S} \quad (2)$$

$$R_{TA}' = \frac{V_{TRACK}}{\frac{V_{FB}}{R_{FB}} + \frac{V_{FB}}{R_{FA}} - \frac{V_{TRACK}}{R_{TB}}} \quad (3)$$

where  $V_{TRACK} \approx 0.8V$ .

Note that large ratios of slave ramp rate to master ramp rate,  $S_S/S_M$ , may result in negative values for  $R_{TA}'$ . If sufficiently large delay is used in step 3,  $R_{TA}$  will be positive, otherwise  $S_S/S_M$  must be reduced.

#### 3. Choose $R_{TA}$ to obtain the desired delay.

If no delay is required, such as in coincident and ratiometric tracking, then simply set  $R_{TA} = R_{TA}'$ . If a delay is desired, as in offset tracking and supply sequencing, calculate  $R_{TA}''$  to determine the value of  $R_{TA}$  where  $t_D$  is the desired delay.

$$R_{TA}'' = \frac{V_{TRACK} \cdot R_{TB}}{t_D \cdot S_M} \quad (4)$$

$$R_{TA} = R_{TA}' || R_{TA}'' \quad (5)$$

the parallel combination of  $R_{TA}'$  and  $R_{TA}''$

As noted in step 2, small delays and large ratios of slave ramp rate to master ramp rate (usually only seen in sequencing) may result in solutions with negative values for  $R_{TA}$ . In such cases, either the delay must be increased or the ratio of slave ramp rate to master ramp rate must be reduced.

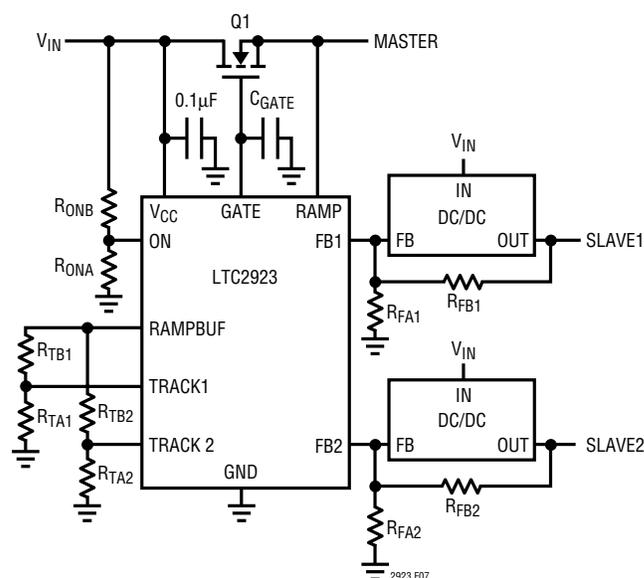


Figure 7. Three Supply Application

## APPLICATIONS INFORMATION

## Coincident Tracking Example

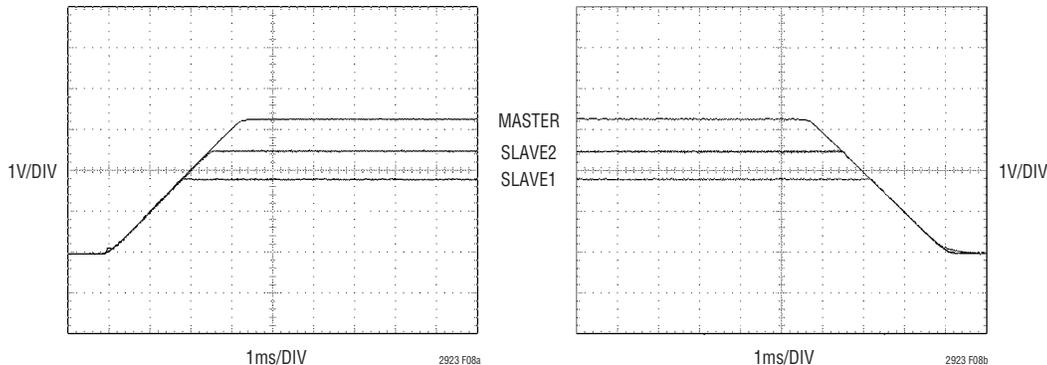


Figure 8. Coincident Tracking (From Figure 9)

A typical three supply application is shown in Figure 9. The master signal is a 3.3V module. The slave 1 supply is a 1.8V switching power supply and the slave 2 supply is a 2.5V switching power supply. Both slave supplies track coincidentally with the 3.3V supply that is controlled with an external FET. The ramp rate of the supplies is 1000V/s. The 3-step design procedure detailed previously can be used to determine component values. Only the slave 1 supply is considered here as the procedure is the same for the slave 2 supply.

1. Set the ramp rate of the master signal.

From Equation 1:

$$C_{GATE} = \frac{10\mu A}{1000V/s} = 10nF$$

2. Solve for the pair of resistors that provide the desired slave supply behavior, assuming no delay.

From Equation 2:

$$R_{TB} = 16.5k\Omega \cdot \frac{1000V/s}{1000V/s} = 16.5k\Omega$$

From Equation 3:

$$R_{TA}' = \frac{0.8V}{\frac{1.235V}{16.5k\Omega} + \frac{1.235V}{35.7k\Omega} - \frac{0.8V}{16.5k\Omega}} \approx 13k\Omega$$

3. Choose  $R_{TA}$  to obtain the desired delay.

Since no delay is desired,  $R_{TA} = R_{TA}'$

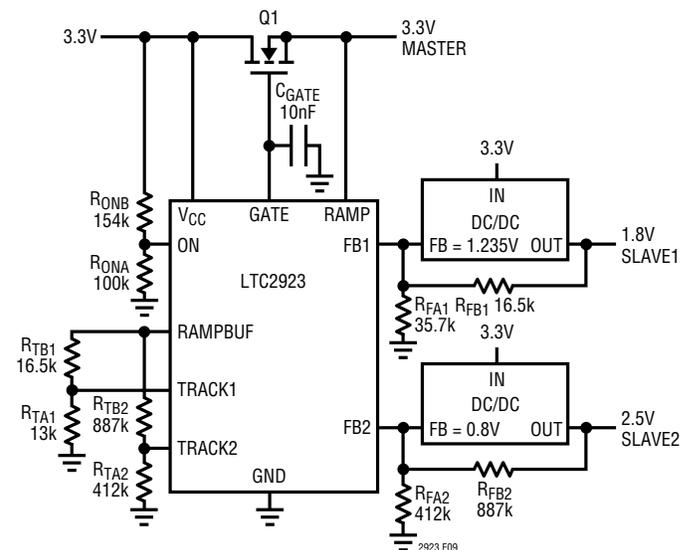


Figure 9. Coincident Tracking Example

In this example, all supplies remain low while the ON pin is held below 1.23V. When the ON pin rises above 1.23V, 10 $\mu$ A pulls up  $C_{GATE}$  and the gate of the FET at 1000V/s. As the gate of the FET rises, the source follows and pulls up the output to 3.3V at 1000V/s. This output serves as the master signal and is buffered from the RAMP pin to the RAMPBUF pin. As this output and the RAMPBUF pin rise, the current from the TRACK pins is reduced. Consequently, the voltage at the slave supply's outputs is reduced, and the slave supplies track the master supply. When the ON pin is again pulled below 1.23V, 10 $\mu$ A will pull down  $C_{GATE}$  and the gate of the FET at 1000V/s. If the loads on the outputs are sufficient, all outputs will track down coincidentally at 1000V/s.

## APPLICATIONS INFORMATION

### Ratiometric Tracking Example

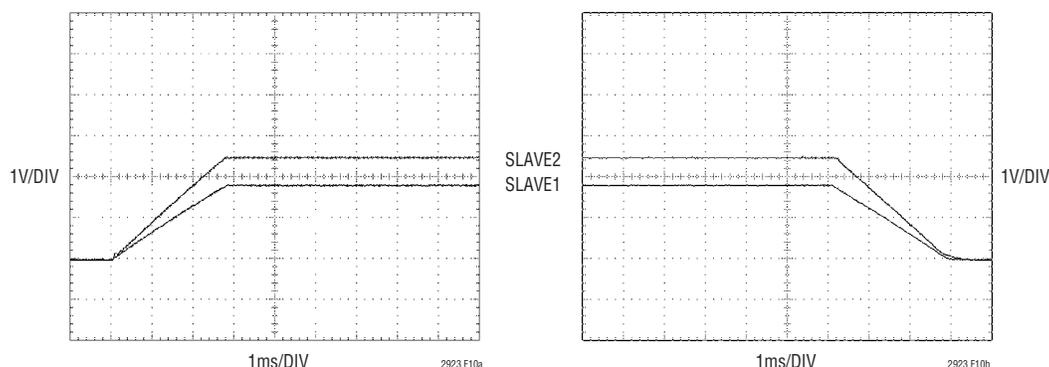


Figure 10. Ratiometric Tracking (From Figure 11)

This example converts the coincident tracking example to the ratiometric tracking profile shown in Figure 10, using two supplies without an external FET. The ramp rate of the master signal remains unchanged (Step 1) and there is no delay in ratiometric tracking (Step 3), so only the result of step 2 in the 3-step design procedure needs to be considered. In this example, the ramp rate of the 1.8V slave 1 supply ramps up at 600V/s and the 2.5V slave 2 supply ramps up at 850V/s. Always verify that the chosen ramp rate will allow the supplies to ramp-up completely before RAMPBUF reaches  $V_{CC}$ . If the 1.8V supply were to ramp-up at 500V/s it would only reach 1.65V because the RAMPBUF signal would reach its final value of  $V_{CC} = 3.3V$  before the slave supply reached 1.8V.

- Solve for the pair of resistors that provide the desired slave supply behavior, assuming no delay.

From Equation 2:

$$R_{TB} = 16.5k\Omega \cdot \frac{1000V/s}{600V/s} \approx 27.4k\Omega$$

From Equation 3:

$$R_{TA}' = \frac{0.8V}{\frac{1.235V}{16.5k\Omega} + \frac{1.235V}{35.7k\Omega} - \frac{0.8V}{27.5k\Omega}} = 10k\Omega$$

Step 3 is unnecessary because there is no delay, so  $R_{TA} = R_{TA}'$ .

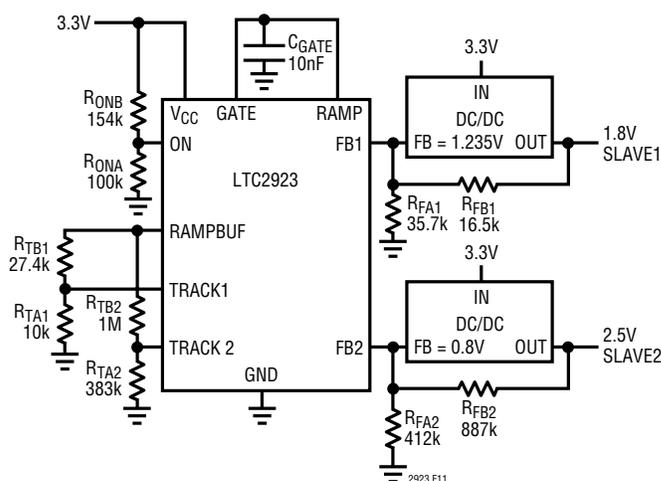


Figure 11. Ratiometric Tracking Example

## APPLICATIONS INFORMATION

### Offset Tracking Example

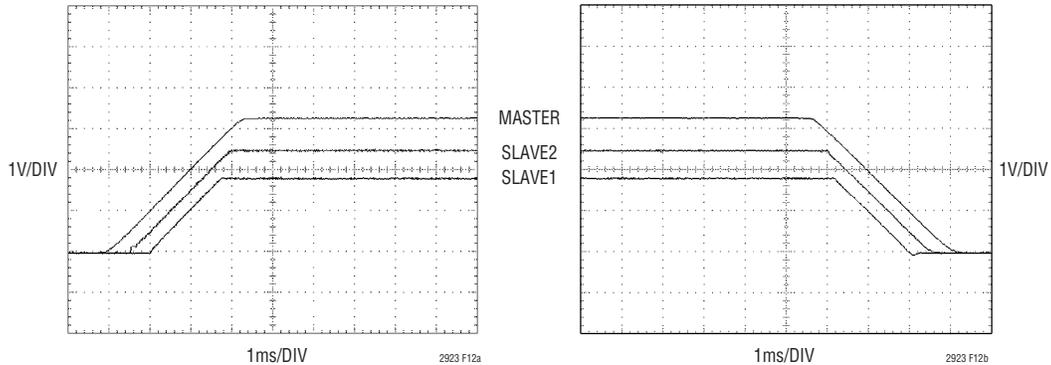


Figure 12. Offset Tracking (From Figure 13)

Converting the circuit in the coincident tracking example to the offset tracking shown in Figure 12 is relatively simple. Here the 1.8V slave 1 supply ramps up 0.5V below the master. The ramp rate remains the same (1000V/s), so there are no changes necessary to steps 1 and 2 of the 3-step design procedure. Only step 3 must be considered. Be sure to verify that the chosen voltage offsets will allow the slave supplies to ramp up completely. In this example, if the voltage offset were 2V, the slave supply would only ramp up to  $3.3V - 2V = 1.3V$ .

3. Choose  $R_{TA}$  to obtain the desired delay.

First, convert the desired voltage offset,  $V_{OS}$ , to a delay,  $t_D$ , using the ramp rate:

$$t_D = \frac{V_{OS}}{S_S} = \frac{1V}{1000V/s} = 1ms \quad (6)$$

From Equation 4:

$$R_{TA}'' = \frac{0.8V \cdot 16.5k\Omega}{1ms \cdot 1000V/s} = 13.2k\Omega$$

From Equation 5:

$$R_{TA} = 13.1k\Omega || 13.2k\Omega \approx 6.65k\Omega$$

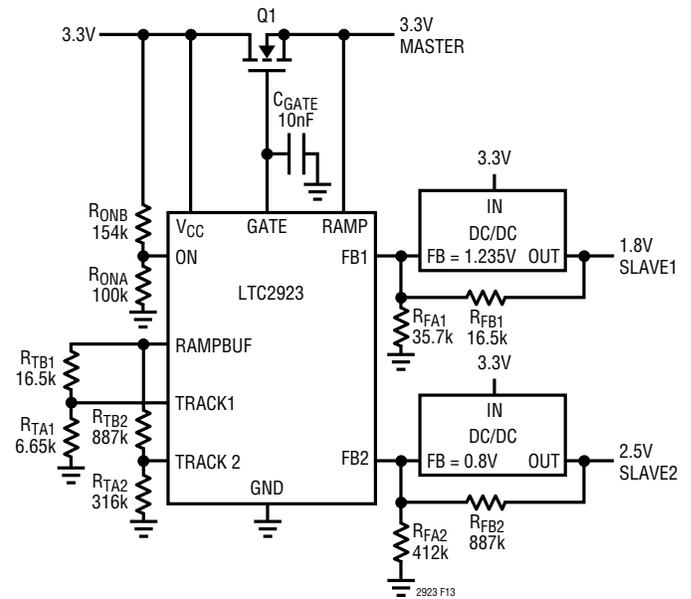


Figure 13. Offset Tracking Example

## APPLICATIONS INFORMATION

### Supply Sequencing Example

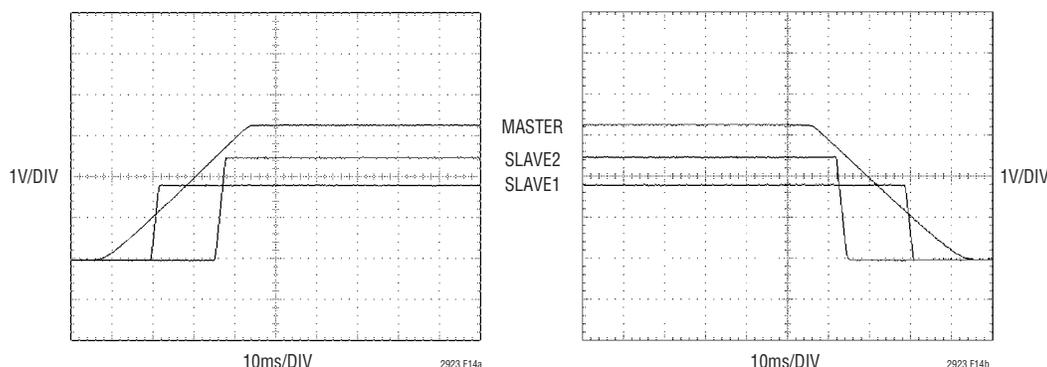


Figure 14. Supply Sequencing (From Figure 15)

In Figure 14, the slave 1 supply and the slave 2 supply are sequenced instead of tracking. The 3.3V supply ramps up at 100V/s with an external FET and serves as the master signal. The 1.8V slave 1 supply ramps up at 1000V/s beginning 10ms after the master signal starts to ramp up. The 2.5V slave 2 supply ramps up at 1000V/s beginning 25ms after the master signal begins to ramp up. Note that not every combination of ramp rates and delays is possible. Small delays and large ratios of slave ramp rate to master ramp rate may result in solutions that require negative resistors. In such cases, either the delay must be increased or the ratio of slave ramp rate to master ramp rate must be reduced. In this example, solving for the slave 1 supply yields:

1. Set the ramp rate of the master signal.

From Equation 1:

$$C_{\text{GATE}} = \frac{10\mu\text{A}}{100\text{V/s}} = 100\text{nF}$$

2. Solve for the pair of resistors that provide the desired slave supply behavior, assuming no delay.

From Equation 2:

$$R_{\text{TB}} = 16.5\text{k}\Omega \cdot \frac{100\text{V/s}}{1000\text{V/s}} = 1.65\text{k}\Omega$$

From Equation 3:

$$R_{\text{TA}}' = \frac{0.8\text{V}}{\frac{1.235\text{V}}{16.5\text{k}\Omega} + \frac{1.235\text{V}}{35.7\text{k}\Omega} - \frac{0.8\text{V}}{1.65\text{k}\Omega}} = -2.13\text{k}\Omega$$

3. Choose  $R_{\text{TA}}$  to obtain the desired delay.

From Equation 4:

$$R_{\text{TA}}'' = \frac{0.8\text{V} \cdot 1.65\text{k}\Omega}{10\text{ms} \cdot 100\text{V/s}} = 1.32\text{k}\Omega$$

From Equation 5:

$$R_{\text{TA}} = -2.13\text{k}\Omega || 1.32\text{k}\Omega = 3.48\text{k}\Omega$$

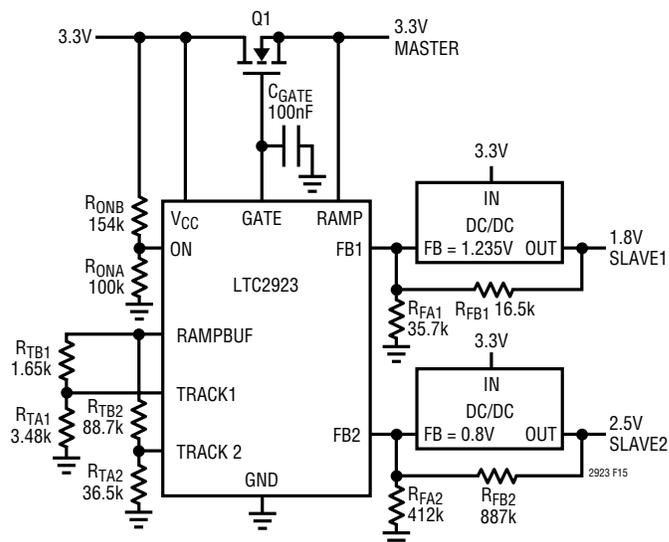


Figure 15. Supply Sequencing Example

## APPLICATIONS INFORMATION

### Final Sanity Checks

The collection of equations below is useful for identifying unrealizable solutions.

As stated in step 2, the slave supply must finish ramping before the master signal has reached its final voltage. This can be verified by the following equation:

$$V_{\text{TRACK}} \left( 1 + \frac{R_{\text{TB}}}{R_{\text{TA}}} \right) < V_{\text{CC}}, \text{ where } V_{\text{TRACK}} = 0.8\text{V}$$

It is possible to choose resistor values that require the LTC2923 to supply more current than the Electrical Characteristics table guarantees. To avoid this condition, check that  $I_{\text{TRACK}x}$  does not exceed 1mA and  $I_{\text{RAMPBUF}}$  does not exceed  $\pm 2\text{mA}$ .

To confirm that  $I_{\text{TRACK}x} < 1\text{mA}$ , the TRACKx pin's maximum guaranteed current, verify that:

$$\frac{V_{\text{TRACK}}}{R_{\text{TA}} \parallel R_{\text{TB}}} < 1\text{mA}$$

Finally, check that the RAMPBUF will not be forced to sink more than 2mA when it is at 0V or be forced to source more than 2mA when it is at  $V_{\text{CC}}$ .

$$\frac{V_{\text{TRACK}}}{R_{\text{TA1}} \parallel R_{\text{TB1}}} + \frac{V_{\text{TRACK}}}{R_{\text{TA2}} \parallel R_{\text{TB2}}} < 2\text{mA} \text{ and}$$

$$\frac{V_{\text{CC}}}{R_{\text{TA1}} + R_{\text{TB1}}} + \frac{V_{\text{CC}}}{R_{\text{TA2}} + R_{\text{TB2}}} < 2\text{mA}$$

### Load Requirements

When the supplies are ramped down quickly, either the load or the supply itself must be capable of sinking enough current to support the ramp rate. For example, if there is a large output capacitance on the supply and a weak resistive load, supplies that do not sink current will have their falling ramp rate limited by the RC time constant of the load and the output capacitance. Figure 16 shows the case when the 2.5V supply does not track the 1.8V and 3.3V supplies near ground.

### Start-Up Delays

Often power supplies do not start-up immediately when their input supplies are applied. If the LTC2923 tries to

ramp-up these power supplies as soon as the input supply is present, the start-up of the outputs may be delayed, defeating the tracking circuit (Figure 17). Often this delay is intentionally configured by a soft-start capacitor. This can be remedied either by reducing the soft-start capacitor on the slave supply or by including a capacitor in the ON pin's resistive divider to delay the ramp up. See Figure 18.

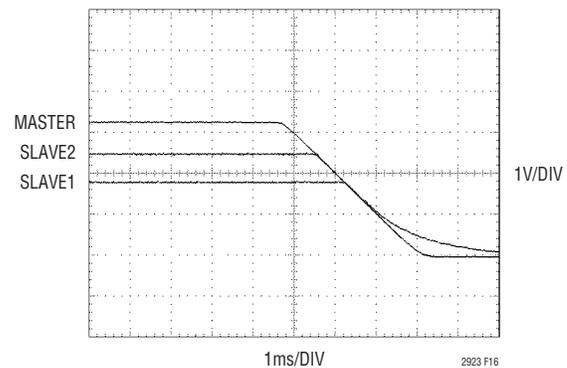


Figure 16. Weak Resistive Load

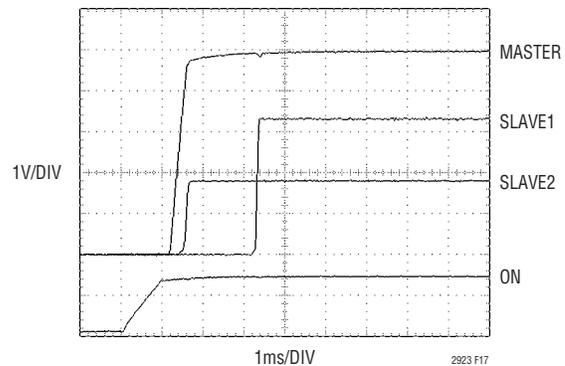


Figure 17. Power Supply Start-Ups Delayed

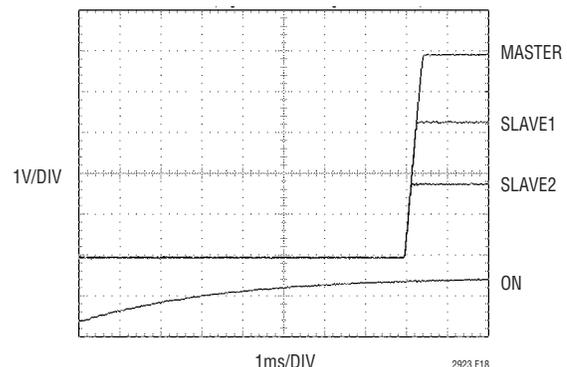


Figure 18. ON Pin Delayed

## APPLICATIONS INFORMATION

### Layout Considerations

Be sure to place a 0.1µF bypass capacitor as near as possible to the supply pin of the LTC2923.

To minimize the noise on the slave supplies' outputs, keep the traces connecting the FBx pins of the LTC2923 and the feedback nodes of the slave supplies as short as possible. In addition, do not route those traces next to signals with fast transition times. In some circumstances it might be advantageous to add a resistor near the feedback node of the slave supply in series with the FBx pin of the LTC2923.

This resistor must not exceed:

$$R_{\text{SERIES}} = \frac{1.5V - V_{\text{FB}}}{I_{\text{MAX}}} = \frac{1.5V}{R_{\text{FA}} \parallel R_{\text{FB}}} - 1$$

This resistor is most effective if there is already a capacitor at the feedback node of the slave supply (often a compensation component). Increasing the capacitance on a slave supply's feedback node will further improve the noise immunity, but could affect the stability and transient response of the supply.

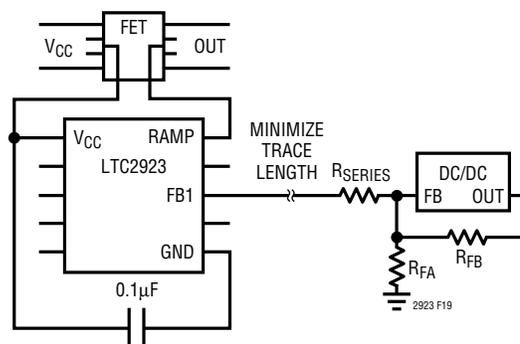
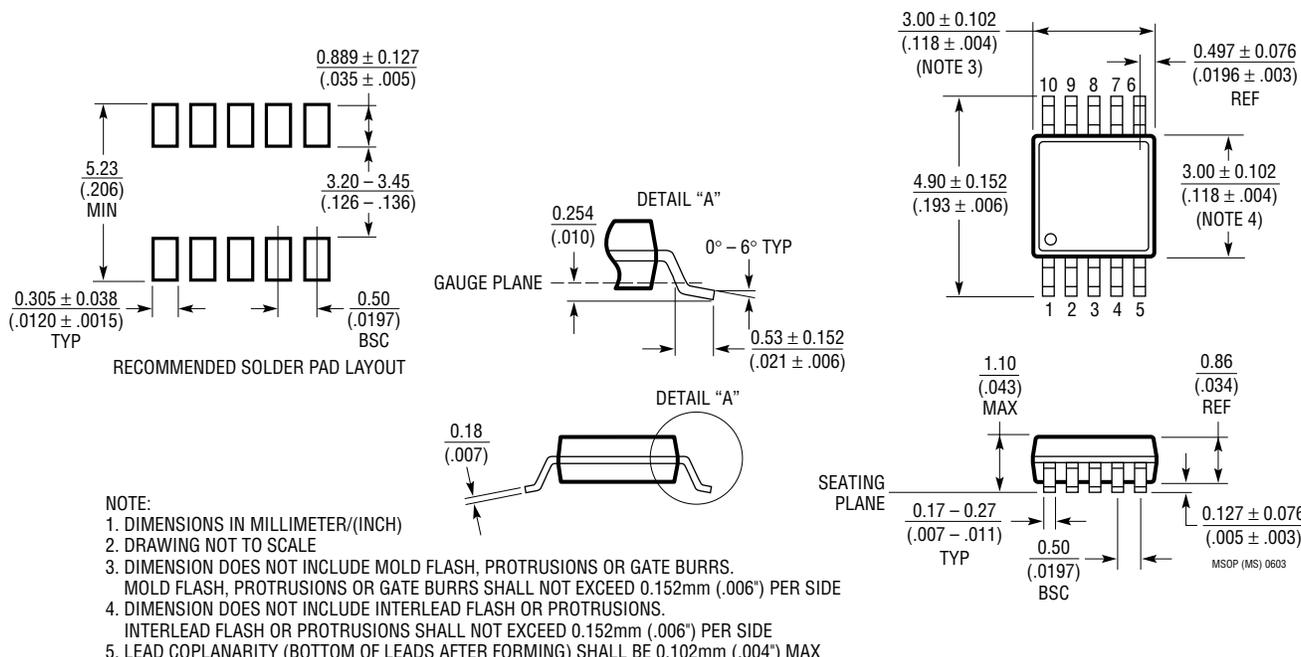


Figure 19. Layout Considerations

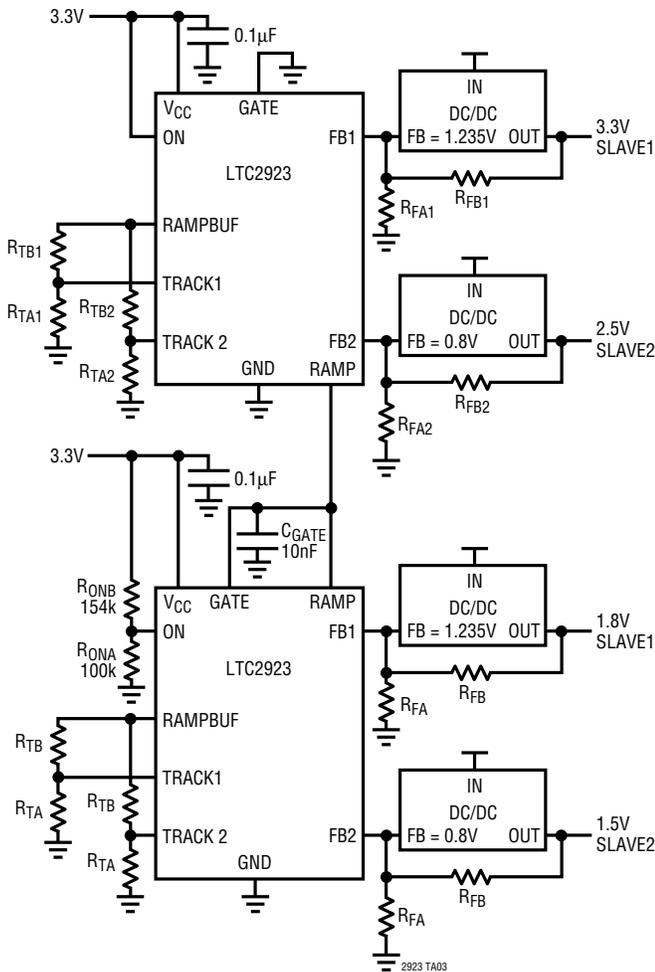
## PACKAGE DESCRIPTION

### MS Package 10-Lead Plastic MSOP (Reference LTC DWG # 05-08-1661)

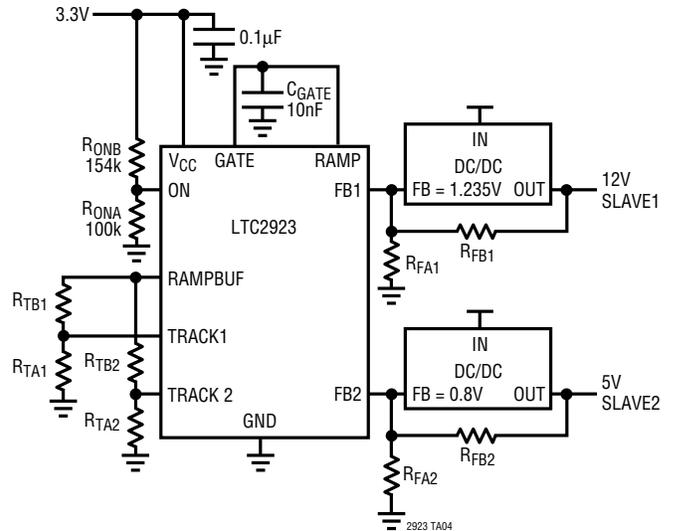


TYPICAL APPLICATIONS

Daisy-Chained Application



High Voltage Supply Application



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1645	Dual Hot Swap™ Controller	Operates from 1.2V to 12V, Allows Supply Sequencing
LTC2920	Power Supply Margining Controller	Single or Dual Versions, Symmetric/Symmetric High and Low Margining
LTC2921/LTC2922	Power Supply Tracker with Input Monitors	Includes 3 (LTC2921) or 5 (LTC2922) Remote Sense Switches
LT®4220	Dual Supply Hot Swap Controller	±2.7V to ±16.5V, Supply Tracking Mode
LTC4230	Triple Hot Swap Controller with Multifunction Current Control	1.7V to 16.5V, Active Inrush Limiting, Fast Comparator
LTC4253	–48V Hot Swap Controller and Supply Sequencer	Floating Supply from –15V, Active Current Limiting, Enables Three DC/DC Converters

Hot Swap is a trademark of Linear Technology Corporation.